Diode Semiconductor Device - Page 1 of 1



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#### **Inclosure Material:**

Metal

**Overall Length:** 

0.450 inches

### **Mounting Facility Quantity:**

1

Joint Electronic Device Engineering Council/jedec/case Outline Designation:

#### Do-5

**Mounting Method:** 

Threaded stud

#### **Features Provided:**

Hermetically sealed case

**Overall Width Across Flats:** 

0.687 inches

Thread Size:

# 0.250 inches

Semiconductor Material:

Silicon

### Voltage Rating In Volts Per Characteristic:

400.0 reverse voltage, instantaneous and 400.0 working peak reverse voltage, peak total value

### **Current Rating Per Characteristic:**

35.00 amperes forward current, average absolute

## Maximum Operating Tempurature Per Measurement Point:

175.0 degrees celsius ambient air

### **Test Data Document:**

81349-mil-s-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.).

### **Thread Series Designator:**

Unf

# Terminal Type And Quantity:

1 tab, solder lug and 1 threaded stud

# **Specification Data:**

81349-mil-s-19500/297 government specification

## Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

No

Fiig:

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